

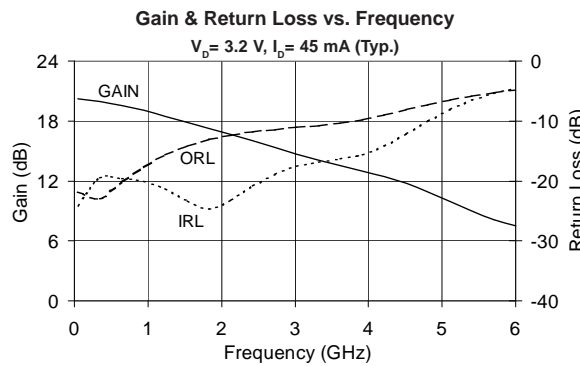


Product Description

The SGA4463Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.

Optimum Technology Matching® Applied

- GaAs HBT
- GaAs MESFET
- InGaP HBT
- SiGe BiCMOS
- Si BiCMOS
- SiGe HBT
- GaAs pHEMT
- Si CMOS
- Si BJT
- GaN HEMT
- InP HBT
- RF MEMS
- LDMOS



Features

- High Gain: 17 dB at 1950 MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Small Signal Gain	17.5	19.0	21.0	dB	850 MHz
		17.0		dB	1950 MHz
		16.0		dB	2400 MHz
Output Power at 1dB Compression		14.0		dBm	850 MHz
		12.3		dBm	1950 MHz
Output Third Intercept Point		27.0		dBm	850 MHz
		24.8		dBm	1950 MHz
Bandwidth Determined by Return Loss		3500		MHz	>9 dB
Input Return Loss		24.4		dB	1950 MHz
Output Return Loss		12.8		dB	1950 MHz
Noise Figure		2.8		dB	1950 MHz
Device Operating Voltage	2.9	3.2	3.5	V	
Device Operating Current	41	45	49	mA	
Thermal Resistance (Junction - Lead)		255		°C/W	

Test Conditions: $V_S = 8 \text{ V}, I_D = 45 \text{ mA Typ.}, OIP_3 \text{ Tone Spacing} = 1 \text{ MHz}, P_{OUT} \text{ per tone} = -5 \text{ dBm}, R_{BIAS} = 110 \Omega, T_L = 25^\circ \text{ C}, Z_S = Z_L = 50 \Omega$

Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current (I_D)	90	mA
Max Device Voltage (V_D)	5	V
Max RF Input Power	+18	dBm
Max Junction Temp (T_J)	+150	°C
Operating Temp Range (T_L)	-40 to +85	°C
Max Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH, J-I}$$



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

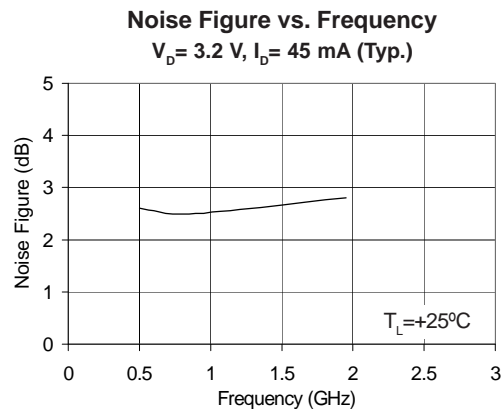
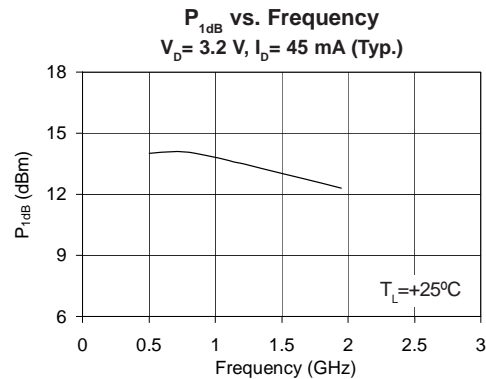
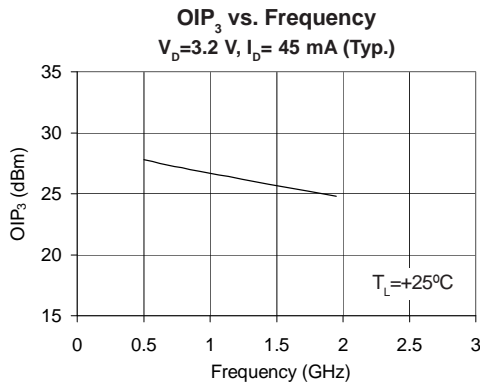


RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

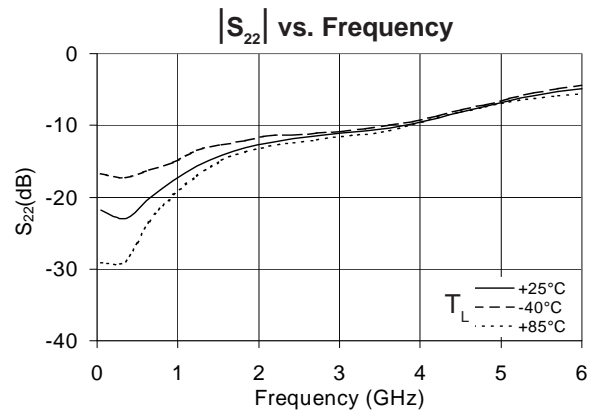
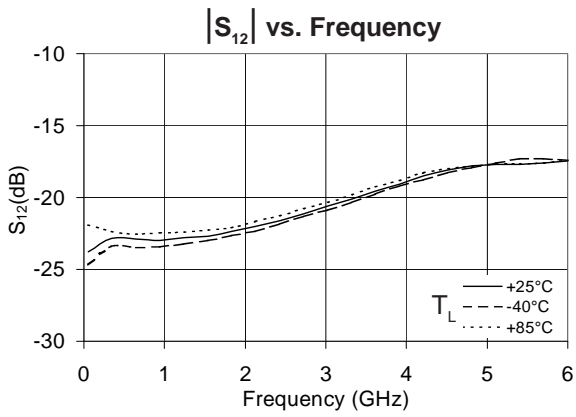
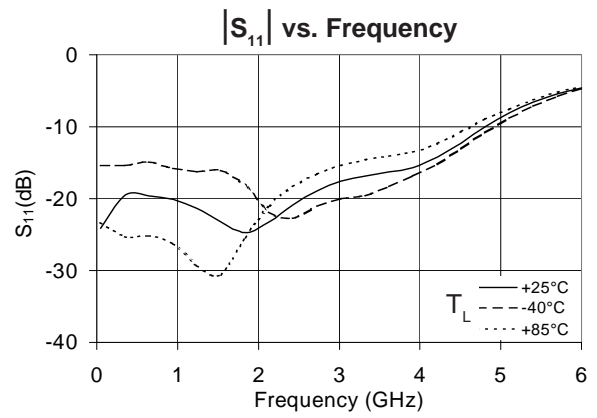
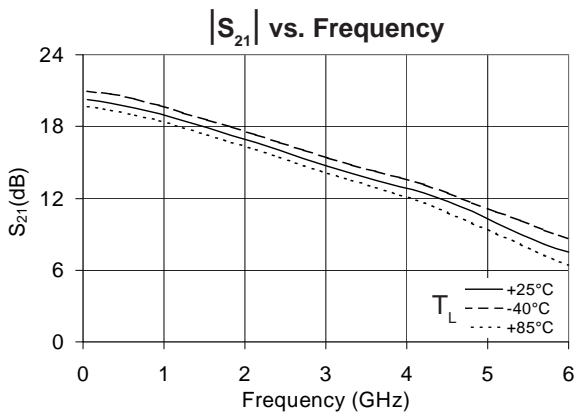
Typical Performance at Key Operating Frequencies

Parameter	Unit	100 MHz	500 MHz	850 MHz	1950 MHz	2400 MHz	3500 MHz
Small Signal Gain	dB	20.2	19.8	19.0	17.0	16.0	13.7
Output Third Order Intercept Point	dBm		27.8	27.0	24.8		
Output Power at 1dB Compression	dBm		14.0	14.0	12.3		
Input Return Loss	dB	22.5	19.5	19.9	24.4	21.1	16.5
Output Return Loss	dB	22.8	21.7	18.4	12.8	11.9	10.5
Reverse Isolation	dB	23.4	22.8	23.0	22.2	21.7	19.8
Noise Figure	dB		2.6	2.5	2.8		

Test Conditions: $V_S = 8V$, $I_D = 45\text{ mA Typ.}$, OIP₃ Tone Spacing = 1MHz, P_{OUT} per tone = -5dBm, R_{BIAS} = 110Ω, T_L = 25°C, Z_S = Z_L = 50Ω

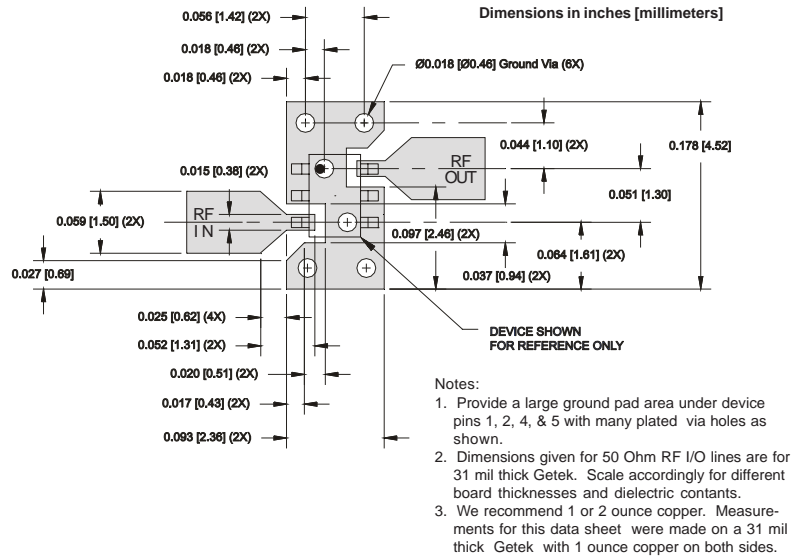


Typical RF Performance Over Temperature (Bias: $V_D = 3.2$ V, $I_D = 45$ mA (Typ.))



Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
1, 2, 4, 5	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
6	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC-blocking capacitor is necessary for proper operation.

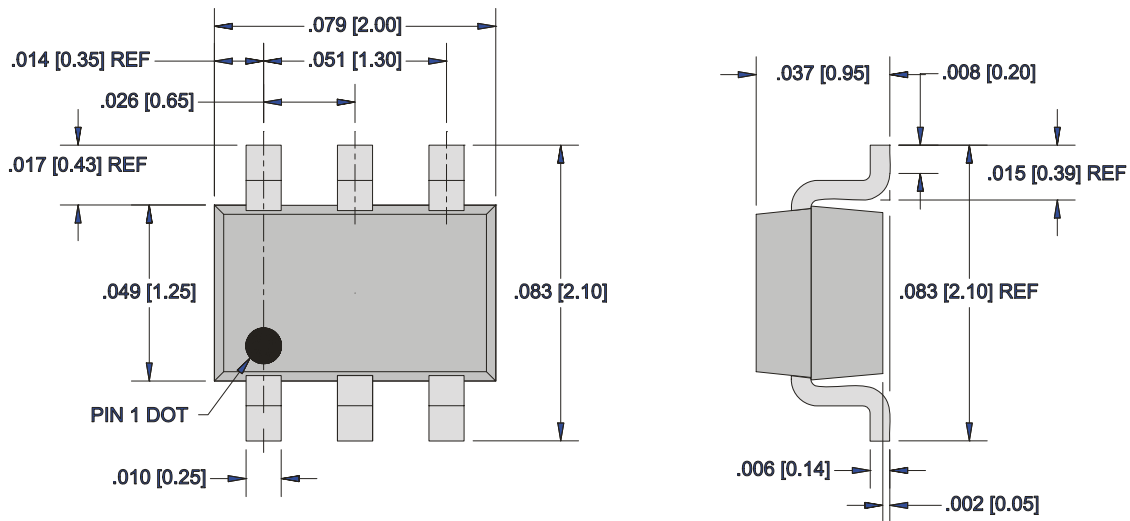
Suggested Pad Layout



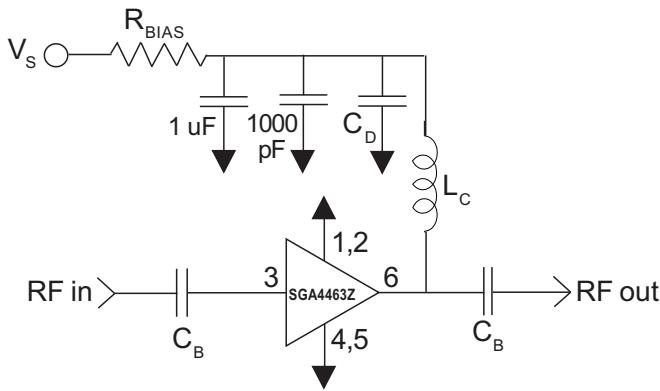
Package Drawing

Dimensions in inches (millimeters)

Refer to drawing posted at www.rfmd.com for tolerances.



Application Schematic

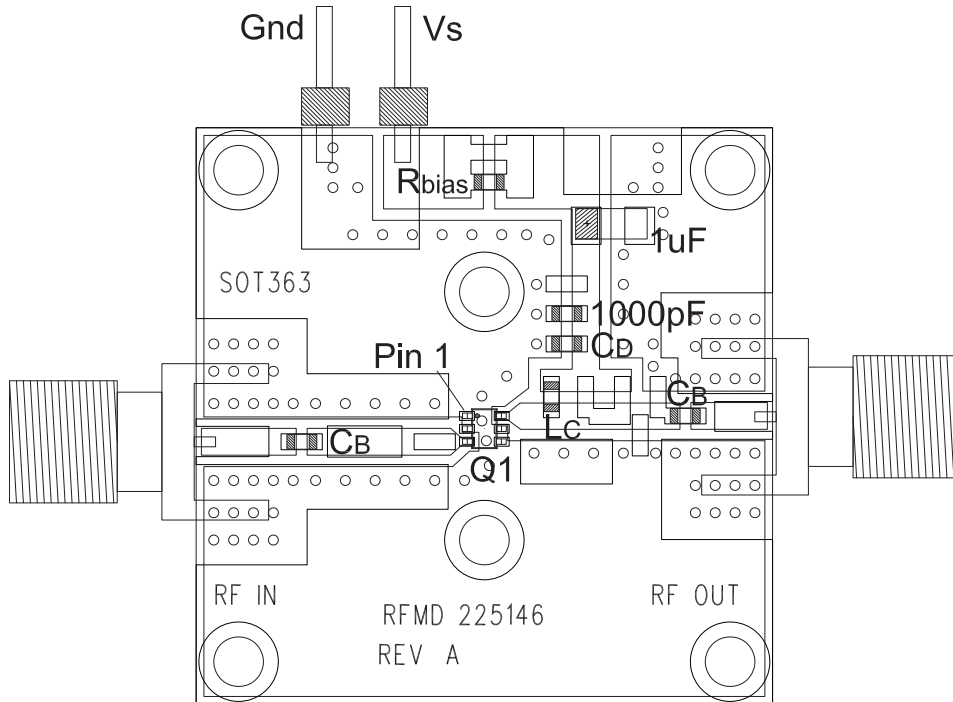


Reference Designator	Frequency (Mhz)				
	500	850	1950	2400	3500
C _b	220 pF	100 pF	68 pF	56 pF	39 pF
C _d	100 pF	68 pF	22 pF	22 pF	15 pF
L _c	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for I _b =45mA				
$R_{BIAS} = (V_S - V_D) / I_D$				
Supply Voltage(V _s)	6 V	8 V	10 V	12 V
R _{BIAS}	62 Ω	110 Ω	150 Ω	200 Ω

Note: R_{BIAS} provides DC bias stability over temperature.

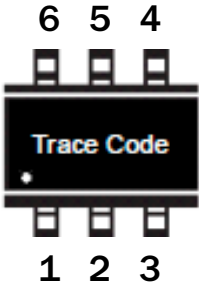
Evaluation Board Layout



Mounting Instructions:

1. Use a large ground pad area near device pins 1, 2, 4, and 5 with many plated through-holes, as shown.
2. We recommend 1 or 2 ounces copper. Measurements for this data sheet were made on a 31mil thick FR-4 board with 1 ounce copper on both sides.

Part Identification Marking



Ordering Information

Ordering Code	Description
SGA4463Z	7" Reel with 3000 pieces
SGA4463ZSQ	Sample bag with 25 pieces
SGA4463ZSR	7" Reel with 100 pieces
SGA4463ZPCK1	850MHz, 8V Operation PCBA with 5-piece sample bag

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [RF Amplifier](#) category:

Click to view products by [Qorvo](#) manufacturer:

Other Similar products are found below :

[A82-1](#) [BGA622H6820XTSA1](#) [BGA 728L7 E6327](#) [BGB719N7ESDE6327XTMA1](#) [HMC397-SX](#) [HMC405](#) [HMC561-SX](#) [HMC8120-SX](#)
[HMC8121-SX](#) [HMC-ALH382-SX](#) [HMC-ALH476-SX](#) [SE2433T-R](#) [SMA3101-TL-E](#) [SMA39](#) [A66-1](#) [A66-3](#) [A67-1](#) [LX5535LQ](#) [LX5540LL](#)
[MAAM02350](#) [HMC3653LP3BETR](#) [HMC549MS8GETR](#) [HMC-ALH435-SX](#) [SMA101](#) [SMA32](#) [SMA411](#) [SMA531](#) [SST12LP19E-QX6E](#)
[WPM0510A](#) [HMC5929LS6TR](#) [HMC5879LS7TR](#) [HMC1126](#) [HMC1087F10](#) [HMC1086](#) [HMC1016](#) [SMA1212](#) [MAX2689EWS+T](#)
[MAAMSS0041TR](#) [MAAM37000-A1G](#) [LTC6430AIUF-15#PBF](#) [CHA5115-QDG](#) [SMA70-2](#) [SMA4011](#) [A231](#) [HMC-AUH232](#) [LX5511LQ](#)
[LX5511LQ-TR](#) [HMC7441-SX](#) [HMC-ALH310](#) [XD1001-BD-000V](#)